

Spin polarised carrier injection into high T_c superconductors : A test for the superconductivity mechanism ?

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We point out in this short communique, that be it a s-wave or d-wave superconductor, in a non equilibrium situation(i.e. in presence of excess unpolarised/polarised quasi-particles maintained by an injection current) the superconducting gap suppression by the presence of same amount excess quasi-particles, can at best differ by a factor of 2, for a conventional BCS superconductor. For the high T_c superconductors on the other hand, there is a huge difference in gap suppression between unpolarised/polarised quasiparticle injection, as observed in the experiments¹. We argue that this this large anomaly has a natural explanation within the *Interlayer tunneling mechanism* of Wheatley, Hsu and Anderson⁷, and is due to the excess polarised quasiparticles blocking the interlayer pair tunneling process. We also point out that spin polarised quasi-particle injection in a superconductor is a very easy way to distinguish between a s-wave or an anisotropic gap superconductor.

Keyword: High T_c superconductors, Spin polarised tunneling, Interlayer pair tunneling.

Spin polarised electron tunneling from ferromagnetic metals to superconductors¹ or strongly correlated metals have recently generated much interest. The focus is on trying to understand spin dependent transport properties of electrons, spin relaxation and possible superconducting devices. One is also interested in the mechanisms of superconductivity suppression(like reduction in critical currents) due to tiny injected tunneling currents(unpolarised/polarised) across an insulating junction into the superconductor.

Though original experiments on spin polarised tunneling in superconductors were carried out in the seventies by Tedrow and Meservey² and first theoretical attempt was made by Aronov³ recently this subject has caught the attention of the physics community due to discovery of lanthanam manganite(CMR materials). In these materials the degree of polarisation of the charge carriers is close to unity(almost perfect ferromagnetic metal).

Both these experiments¹ are done in the 3-layer structure like, HSTC/I/Manganite, where a high T_c superconductor(HSTC) thin film is separated from a ferromagnetic metallic underlayere(Manganite) by an insulating(I) layer. The critical current of the HSTC film is found to drop precipitously as a function of a tiny injection current pushed from the ferromagnetic metal through the insulating junction into the HSTC film. When Manganite is replaced by Au(an ordinary paramagnetic metal) , then it is found that for the same amount of injected current the drop in the critical current of the HSTC film is much smaller. The fractional change in critical current for polarised and unpolarised injection currents(over the same injection current interval)differs by an order of magnitude.

The mechanism determining the critical current of a superconducting film is very complex. However critical current suppression should be related to the order parameter suppression and the puzzle is why spin polarised injected carriers are so damaging to superconductivity in the high T_c materials.

In this paper we try to show that the large difference between polarised/unpolarised injection current is very special only to the high T_c superconductors. We predict that if the high T_c superconductor is replaced by an ordinary BCS superconductor then the relative difference in superconducting gap suppression in the two cases is not at all that striking(differs by at most a factor of 2 !!). This is our main result. In other words spin polarised electron tunneling into high T_c superconductors can be used to understand the mechanism of superconductivity in the high T_c materials.

The suppression of superconducting gap due to unpolarised quasiparticle overpopulation(a non-equilibrium situation) was first investigated theoretically by Owen and Scalapino⁴. They examined a simple model of an electron gas containing both Cooper pairs and excited quasi-particles with the ratio of paired to unpaired electrons being artificially specified, instead of being uniquely determined by the temperature, as is usual, in the thermal equilibrium situation for an isolated superconductor. The system is considered as being in thermal equilibrium although the paired and unpaired electrons are not in chemical equilibrium. It is assumed that for small amount of excess injected carriers, the time for pair recombination is much larger that the time for the injected quasiparticles to thermalize with the lattice. This is achieved by introducing a chemical potential for the quasiparticles different from the pair chemical potential.

The free energy of the superconductor F_s is given by,

$$F_s = 2 \sum_k |\epsilon_k - \mu| (f_k - 2f_k v_k^2 + v_k^2) - \sum_{k,k'} V_{k,k'} u_k v_k u_{k'} v_{k'} (1 - f_k)(1 - f_{k'}) - T \sum_k [f_k \log f_k + (1 - f_k) \log(1 - f_k)] \quad (1)$$

where u_k and v_k has their usual meaning, and $f_k = \langle \gamma_{k,\sigma}^\dagger \gamma_{k,\sigma} \rangle$ is the fermi function for the superconducting quasi-particles and ϵ_k is the dispersion of the electrons in the normal state. However in addition to the usual constrain equation for the total number of electrons $\sum_{k,\sigma} \langle c_{k,\sigma}^\dagger c_{k,\sigma} \rangle = N$ which is enforced by proper choice of the chemical potential μ , an additional constrain on quasi-particle excitation number will be imposed, $\sum_{k,\sigma} f_{k,\sigma} = n \ll N$. This can be done by introducing an extra chemical potential⁵ μ^* so that now, $f_k = [1 + e^{\beta(E_k - \mu^*)}]^{-1}$. The modified BCS gap equation is now,

$$\Delta_k = \sum_{k'} \frac{V_{k,k'} \Delta_{k'}}{2E_{k'}} (1 - f_{k'\uparrow} - f_{-k'\downarrow}) = \sum_{k'} \frac{V_{k,k'} \Delta_{k'}}{2E_{k'}} \tanh \beta/2 (E_{k'} - \mu^*) \quad (2)$$

Asuming a momentum independent $V_{k,k'}$ (s-wave superconductor) and going from momentum summation to energy integration with a cut-off ω_D , we get,

$$\frac{1}{N(E_F)V} = \int_{-\omega_D}^{\omega_D} \frac{d\epsilon}{2E} \tanh \frac{1}{2} \beta (E - \mu^*)$$

The number of excess quasi-particles is,

$$n = 2 \sum_k [f(E_k - \mu^*) - f(E_k)] = 4N(E_F) \int_0^\infty \frac{d\epsilon}{e^{\beta(E - \mu^*)} + 1} \quad (3)$$

the factor of 2 before the momentum summation is because of two spin species.

Defining $n_0 = \frac{n}{4N(E_F)\Delta_0}$, where Δ_0 s the gap at $T = 0$ and $\mu^* = 0$, we can easily solve for the gap value at any T and n from the above two equations. In the limit of zero temperature the gap value can be determined from the algebraic equation,

$$\frac{\Delta_0}{\Delta} = [n_0 \frac{\Delta_0}{\Delta} + \sqrt{1 + n_0^2 \frac{\Delta_0^2}{\Delta^2}}]^2 \quad (4)$$

This is the result of Owen and Scalapino, for excess unpolarised quasiparticles.

For spin polarised quasiparticle injection, we introduce a different chemical potential, for *only the up spin quasiparticles*, i.e. assuming complete spin polarisation of electrons in the ferromagnet. The gap equation (2) will be modified to,

$$\Delta_k = \sum_{k'} \frac{V_{k,k'} \Delta_{k'}}{2E_{k'}} \frac{1}{2} [\tanh \beta/2 (E_{k'} - \mu^*) + \tanh \beta/2 E_{k'}] \quad (5)$$

Corresponding equation for the number of excess quasiparticles will be, same as equation (3) with the factor of 2 missing before the momentum summation, because excess quasiparticles are of only one spin species. In the limit of zero temperature we get the folowing algebraic equation for the normalise gap value,

$$\frac{\Delta_0}{\Delta} = [2n_0 \frac{\Delta_0}{\Delta} + \sqrt{1 + 4n_0^2 \frac{\Delta_0^2}{\Delta^2}}]^2 \quad (6)$$

In figure.1 we show the normalized gap versus extra quasiparticles for a s-wave superconductors (solutions of equations 3 & 4). We find that for, s-wave superconductors, a first order phase transition to normal metal occurs, for $n = 0.15$; $\Delta = 0.63\Delta_0$, and $n = 0.08$; $\Delta = 0.58\Delta_0$ for unpolarised and polarised quasiparticle injections. Beyond this critical concentration of injected carriers, the free energy of the perturbed superconductor becomes larger than normal state free energy. Notice though that, for the same amount of injected carriers, the relative gap suppression in unpolarised/polarised carriers differs by at most by a factor of 2.

Just as at finite temperatures quasi-particle excitations interfere with the pairing interaction and eventually destroy superconductivity at T_c , when an excess number of quasi-particles are injected into the superconductor, it basically reduces the phase space for BCS pair scattering process and reduce the gap value. BCS interaction scatters pairs ($k \uparrow, -k \downarrow$) \rightarrow ($k' \uparrow, -k' \downarrow$) across the fermi surface. So any excess quasiparticle occupying these states limits the phase space for the BCS interaction. It is obvious that when the injected quasi-particles are polarised (all of one spin) they interfere with BCS interaction more severly and hence the gap value falls faster with quasi-particle over-population, compared to the unpolarised injection current.

We next investigate the effect of quasi-particle injection on superconductors with anisotropic gap, specifically gaps of d-wave symmetry. The dispersion of electrons is chosen to be of the form

$$\epsilon(k) = -2t (\cos k_x + \cos k_y) + 4t' \cos k_x \cos k_y - 2t''(\cos 2k_x + \cos 2k_y), \quad (7)$$

with $t = 0.25$ eV, $\frac{t'}{t} = 0.45$, $\frac{t''}{t} = 0.2$. We also choose $\epsilon_F = -0.45$ eV corresponding to a Fermi surface which is closed around the Γ point. These choices are inspired by band structure calculations⁶ for the YBCO compound at optimal doping concentration. The cut off the pairing interaction is chosen to be $\omega_D = 30$ meV, and the pairing interaction strength $V_{k,k'} = V_0 f_k f_{k'}$ with $f_k = \cos(k_x) - \cos(k_y)$ and $V_0 = 2.8$ meV. With this choice of parameters the T_c comes out to be $30^0 K$.

In figure.2 we plot the normalised momentum averaged value of the superconducting gap magnitude, $\Delta(n, T)/\Delta(0, T)$ versus n (quasi-particle over population) for different temperatures. There are some interesting features to be noticed here.

(1) Notice the crossing of curves, for $T = 5$ and $25^0 K$. The origin of this can be seen by looking at the gap equation(2). States of energy E_k less than μ^* interferes with the pairing process by giving a negative contribution to the binding. At low temperatures and small injection currents, the extra carriers occupy the states near the deep gap nodes, where the denominator E_k is also small giving rise to large reduction in binding energy. At larger temperatures(for same amount of injected carriers) on the other hand the quasi-particles are distributed over a larger range of energies(larger denominator) leading to smaller suppression of binding(and hence larger gap values). Larger concentration of injected carriers, of course will ultimately be more damaging to superconductivity, because of larger number of thermally excited quasi-particles that are already present. This leads to the crossing of curves as seen in fig 2. This will be a generic feature for any superconductor with deep gap nodes, and should be easily seen in spin injection experiments.

(2) Notice also that the critical concentration of excess quasi-particles that destroy superconductivity is not a monotonic function of temperature and goes through a maximum around $T_c/2$.

(3) Though it is not shown in the plot, injected current suppresses superconductivity more in the d-wave superconductors, than for a s-wave superconductor having same critical temperature, as one would expect for gap functions with deep nodes.

In figure.3, we have plotted the normalised momentum averaged gap magnitude of a d-wave superconductor, with a T_c of $90^0 K$ versus for both unpolarised/polarised quasi-particle over population(we go upto $n = 0.15$ only). The difference in the reduction of gap values in the unpolarised/polarised tunneling is the range of 2.5 – 5.0%(i.e a factor of 2 only). Clearly the large anomaly observed while tunneling into the high T_c superconductor, as seen in the experiments¹ has its origin in the superconducting mechanism in the high T_c materials itself.

We shall explore here the *interlayer tunneling model* of superconductivity^{7,8}.

We begin by writing the gap equation for interlayer tunneling model with unpolarised injected carriers as,⁸

$$\Delta_k = T_J(k) \frac{\Delta_k}{2E_k} \tanh \frac{\beta(E_k - \mu^*)}{2} + \sum_{kk'} V_{kk'} \frac{\Delta_{k'}}{2E_{k'}} \tanh \frac{\beta(E_{k'} - \mu^*)}{2}, \quad (8)$$

For polarised carrier injection, this equation has to be corrected as shown in equation (5).

This gap equation can be obtained by considering two close Cu-O layers as in YBCO coupled by a Josephson tunneling term of the form

$$H_J = -\frac{1}{t} \sum_k t_{\perp}^2(k) (c_{k\uparrow}^{\dagger} c_{-k\downarrow}^{\dagger} d_{-k\downarrow} d_{k\uparrow} + \text{h.c.}) ,$$

where $t_{\perp}(k)$ is the bare single electron hopping term between the two coupled layers c and d and t is a band structure parameter in the dispersion of electrons along the Cu-O plane. Finally, $T_J(k)$ in the right hand side of equation (1) is given by $T_J(k) = \frac{t_{\perp}^2(k)}{t}$, where $t_{\perp}(k) = \frac{t_{\perp}}{4}(\cos(k_x) - \cos(k_y))^2$. The dispersion of electrons along the Cu-O plane is given by equation 5. Note that the Josephson coupling term in H_J conserves the individual momenta of the electrons that get paired by hopping across the coupled layers. This is as opposed to a BCS scattering term which would only conserve the center of mass momenta of the pairs. This is the origin of all features that are unique to the interlayer tunneling mechanism. This term has a local $U(1)$ invariance in k -space and cannot by itself give a finite T_c . It needs an additional BCS type non local interaction in the planes which could be induced by phonons or residual correlations. Here we assume the inplane pairing interaction to be d-wave kind i.e, $V_{kk'} = V_0 f_k f_{k'}$ with $f_k = \cos k_x - \cos k_y$. $T_J(k)$ can be inferred from electronic structure calculations. As shown in reference⁶, it is adequate to choose $t_{\perp}(k) = \frac{t_{\perp}^2}{4}(\cos k_x - \cos k_y)^2$, with $t_{\perp}/t \equiv 1/3$ to $1/5$. According to Anderson, it is the k -space

locality that leads to a scale of T_c that is linear in interlayer pair tunneling matrix element. He finds that in the limit $T_J > V_{kk'}$, $k_B T_c \approx \frac{T_J}{4}$ and in the other limit, $k_B T_c \approx \hbar \omega_D e^{-\frac{1}{\rho_0 V_0}}$, where ω_D , ρ_0 and V_0 are Debye frequency, density of states at the fermi energy, and fermi surface average matrix element $V_{kk'}$. The important point being that even with a little help from the in plane pairing interaction the interlayer tunneling term can provide a large scale of T_c . In this model the gap value is mainly controlled by the interlayer tunneling amplitude, rather than the inplane pairing interaction, though the symmetry of the gap function is determined overwhelmingly by the inplane BCS kind of interaction strength $V_{k,k'}$. and the gap value is very sensitive to the interlayer pair tunneling amplitude⁹.

In figure.4, we plot the normalised momentum averaged gap values versus both unpolarised/polarised quasi-particle over population upto $n = 0.085$. We find that for $n = 0.085$, the reduction in gap value for unpolarised injection current is about 5%, whereas for the polarised carrier injection is about 35%(that is a factor of 7 !).

The large difference between the two situations(as observed in the experiments¹ also) now shows up. We argue that when polarised carriers are injected, then, over and above the usual dynamical pair breaking(due phse space blocking of BCS interaction)in the planes like in usual BCS superconductors, there is an added inhibition of interlayer pair tunneling. This is so, because there are much less number of extra singlets near the fermi surface, to tunnel from plane to plane. This effect is absent when unpolarised quasiparticles enter the planes. In this mechanism ,*extra quasiparticles directly affect the interlayer pairing tunneling process, which is the main source of superconducting condensation energy gain*. This is over and above the interference in the binding process in the individual layers that we have discussed earlier in usual BCS superconductors.

The introduction of an extra chemical potential μ^* to tackle the nonequilibrium superconductivity, in presence of artificially maintained quasiparticles, is a reasonable starting point, when the excess quasiparticles thermalize with low energy phonons more often than they recombine into pairs. In these limit the quasiparticles are in steady state at T but have an excess number denoted by the increased chemical potential μ^* . One important ingradient of Anderson et al's⁷ mechanism is that, in the normal state the electrons are spin-charge separated and no quasiparticles in the fermi liquid sense exists. We have assumed here that, below the superconducting T_c somehow spin-charge separation is absent. This seems to be the case from photoemission experiments which show clear signal of well defined quasiparticles on the fermi surface.In the superconducting state how exactly it happens, is still not clear.

At the present moment all that we can say is that, because of spin-charge separation in the normal state, the single particles(which are not even well defiend properly) cannot tunnel from plane to plane in a coherent fashion. On the other hand there are indications from some earlier theoretical attempts¹⁰ that electrons can tunnel in pairs. In other words spin-charge separation itself is responsible for pair tunneling. We believe that when some BCS type of pairing interaction is introduced, this anomolous self energy actually leads to weaking of spin charge separation, and electrons recover fermi liquid type quasi-particles below T_c , as it is observed in the photoemission experiments. We have implicitly assumed this while working with the interleyer tunneling mechanism. Clearly a more carefull analysis of this problem is needed within this mechanism.

Throughout this analysis, we have assumed that, (1) the London penetration depth is lesser that the superconducting film thickness, so that direct magnetic field of the ferromagnetic metal does not penetrate the superconductor much. (2) The spin diffusion length is much larger that the SC film thickness, so that no spatial variation of the gap has to be taken into account. This is certainly true when there are no magnetic impurity or for small spin orbit interaction, for the then extra spin density relaxes slowly.

We have also not taken into account the case of finite recombination time for the excess quasiparticles.

It would be interesting to see if, the presence of extra spin polarised quasiparticles will give rise to polarisation field, that will be felt by the nuclear magnetic moment through the contact hyperfine interaction. This will significantly affect the NMR relaxation rate and ESR linewidths.

Recently N. C. Yeh et al¹¹,have observed an initial, actual increase in critical current for low enough injection currents, when the insulating barrier thickness is small. They argue that, some up spin quasiparticles in the superconductors can diffuse into the magnetic materials, creating spin imbalance in the superconductor(more of down spin quasiparticles). On the other hand when the injection current is switched on, then up spin electrons starts coming into the superconductor, nullifying the spin imbalance in the superconductor. That is why T_c increases for small injection currents. For larger injection currents of course T_c falls drastically as is seen in experiments, and as we have argued to be natural within the Interlayer tunneling mechanism of Anderson et al.

While this maybe the case, we would also like to point out, that this initial increase can also happen, when there are some (1) magnetic impurity inside the superconductor or (2) spin-orbit interaction is important. Because the injected polarised carriers will give an internal magnetic field which will polarise the magnetic impurities, so that, they become less effective in breaking pairs. Spin orbit interaction can similarly be counteracted by the internal magnetic field due to spin imbalance in the material, though the spin orbit interaction might be absent in the cuprate superconductors.

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FIG. 1. $\Delta(T = 0, n_0)/\Delta(T = 0, n_0 = 0)$ versus n_0 (the quasi-particle over population, as defined in the text) for s-wave superconductor(the solutions of equations 3 & 4)

FIG. 2. The normalised momentum averaged gap $\Delta(T, n)/\Delta(T, n = 0)$ of a d-wave superconductor, with $T_c = 30^0\text{K}$ versus injected carrier concentration. Solid line is for $T = 5^0\text{K}$, long dashes $T = 10^0\text{K}$, short dashes $T = 15^0\text{K}$, dotted line $T = 20^0\text{K}$ and the dash-dotted line os for $T = 25^0\text{K}$.

FIG. 3. The normalised momentum averaged gap $\Delta(T, n)/\Delta(T, n = 0)$ of a d-wave superconductor, with $T_c = 90^0\text{K}$ versus injected carrier concentration at $T = 10^0\text{K}$. The solid and dashed lines are for unpolarised and polarised injected carriers.

FIG. 4. The normalised momentum averaged gap $\Delta(T, n)/\Delta(T, n = 0)$ of a (d-wave superconductor + interlayer tunneling), with $T_c = 90^0\text{K}$ versus injected carrier concentration at $T = 10^0\text{K}$. The solid and dashed lines are for unpolarised and polarised injected carriers.







